TOSHIBA Photocoupler GaAs IRed&Photo-Triac

TLP665J

Office Machine
Household Use Equipment
Triac Driver
Solid State Relay

The TOSHIBA TLP665J consists of a photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP.

- Peak off-state voltage: 600 V (min.)
- Trigger LED current: 10 mA (max.)
- On-state current: 100 mA (max.)
- UL recognized: UL1577, file No. E67349
- Isolation voltage: 5000 V_{rms} (min.)
- Option (D4) type

VDE approved: DIN VDE0884 / 08.87,

Certificate No. 68383

Maximum operating insulation voltage: 650 VpK Highest permissible over voltage: 6000 VpK

(Note 1) When a VDE0884 approved type is needed, please designate the "option (D4)"

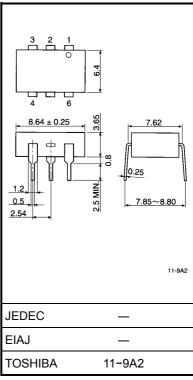
• Structural parameter

Creepage distance: 7.0 mm (min.)

Clearance: 7.0 mm (min.)

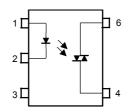
Insulation thickness: 0.5 mm (min.)

Unit in mm



Weight: 0.44 g

Pin Configurations (top view)



- 1 : Anode
- 2 : Cathode
- 3 : NC
- 4 : Terminal 1
- 6 : Terminal 2

Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit	
	Forward current		I _F	50	mA	
	Forward current derating (Ta ≥ 53°	ΔI _F / °C	-0.7	mA / °C		
	Peak forward current (100 µs puls	I _{FP}	1	Α		
TED	Power dissipation	P _D	100	mW		
	Power dissipation derating (Ta ≥ 2	ΔP _D / °C	-1.0	mW / °C		
	Reverse voltage	V _R	5	V		
	Junction temperature	Tj	125	°C		
	Off-state output terminal voltage	V_{DRM}	600	V		
	On-state RMS current	Ta = 25°C		100	- mA	
	On-state Rivis current	Ta = 70°C	I _{T(RMS)}	50		
_	On-state current derating (Ta ≥ 25	ΔI _T / °C	-1.1	mA / °C		
Detector	Peak on-state current (100µs puls	I _{TP}	2	Α		
Det	Peak nonrepetitive surge current (P _W = 10 ms, DC = 10%)	I _{TSM}	1.2	А		
	Total power dissipation	P _D	300	mW		
	Total power dissipation derating (1	ΔP _D / °C	-4.0	mW / °C		
	Junction temperature	Tj	115	°C		
Storage	e temperature range		T _{stg}	-55~125	°C	
Operat	Operating temperature range			−40~100	°C	
Lead s	ead soldering temperature (10 s)		T _{sol}	260	°C	
Total p	ackage power dissipation	ge power dissipation P _T 330		mW		
Total p	ackage power dissipation derating (ΔP _T / °C	-4.4	mW / °C		
Isolatio	Isolation voltage (AC, 1 min., R.H.≤ 60%) (Note 2)			5000	V _{rms}	

(Note 2) Pin 1, 2 and 3 shorted together and pin 4 and 6 shorted together.

Recommended Operating Conditions

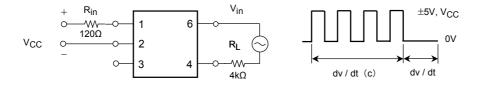
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{AC}	_	_	240	Vac
Forward current	l _F	15	20	25	mA
Peak on-state current	I _{TP}	_	_	1	Α
Operating temperature	T _{opr}	-25	-	85	°C

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Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
LED	Forward voltage	V_{F}	I _F = 10 mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V	_	_	10	μA
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	_	pF
Detector	Peak off-state current	I _{DRM}	V _{DRM} = 600 V	_	10	1000	nA
	Peak on-state voltage	V_{TM}	I _{TM} = 100 mA	_	1.7	3.0	V
	Holding current	lΗ	_	_	1.0	_	mA
	Critical rate of rise of off–state voltage	dv / dv	V _{in} = 240 V _{rms} , Ta = 85°C (Note 3)	_	500	_	V / μA
	Critical rate of rise of commutating voltage	dv / dt (c)	V _{in} = 60 V _{rms} , I _T = 15 mA (Note 3)	_	0.2	_	V / μA

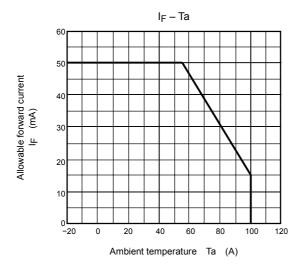
(Note 3) dv / dt test circuit

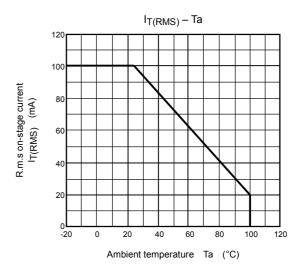


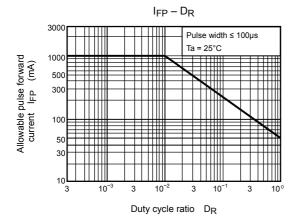
Coupled Electrical Characteristics (Ta = 25°C)

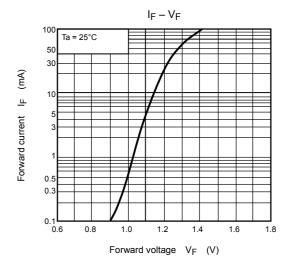
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	V _T = 6 V	_	5	10	mA
Capacitance (input to output)	CS	V _S = 0, f = 1 MHz	_	0.8	1	pF
Isolation resistance	R _S	V _S = 500 V	5×10 ¹⁰	10 ¹⁴	_	Ω
	BV _S	AC, 1 minute	5000	_	-	- V _{rms}
Isolation voltage		AC, 1 second, in oil	_	10000	_	
		DC, 1 minute, in oil	_	10000	-	Vdc

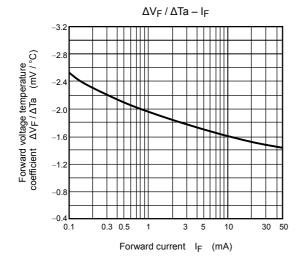
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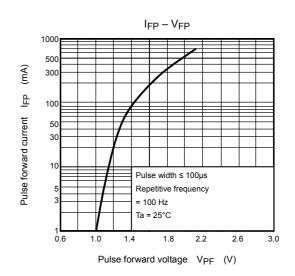


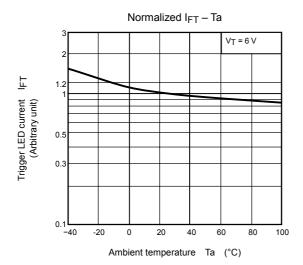


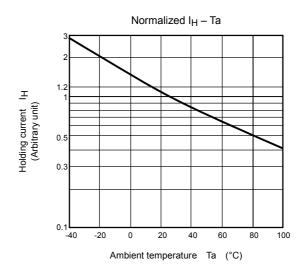


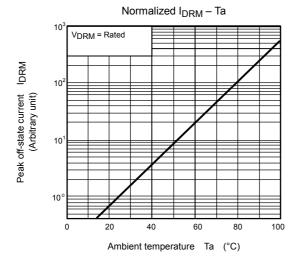


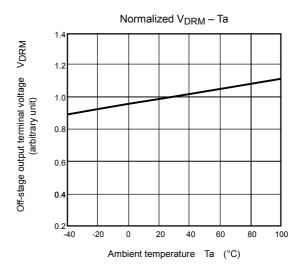


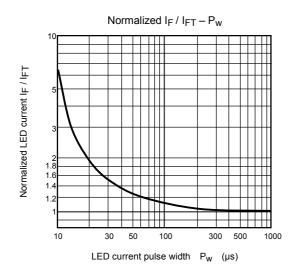












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